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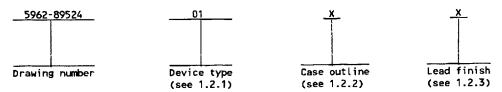
<u>DISTRIBUTION STATEMENT A</u>. Approved for public release; distribution is unlimited.

5962-E028-94

■ 9004708 0001330 989 **■** 

### 1. SCOPE

- 1.1 <u>Scope</u>. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".
  - 1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device type(s). The device type(s) shall identify the circuit function as follows:

Device type	Generic number	Circuit function	Data retention	Access time
01	(See 6.6)	64K X 4 CMOS static RAM	Yes	70 ns
02	(See 6.6)	64K X 4 CMOS static RAM	Yes	55 ns
03	(see 6.6)	64K X 4 CMOS static RAM	Yes	45 ns
04	(see 6.6)	64K X 4 CMOS static RAM	Yes	35 ns
05	(see 6.6)	64K X 4 CMOS static RAM	Yes	25 ns
06	(see 6.6)	64K X 4 CMOS static RAM	No	20 ns
07	(see 6.6)	64K X 4 CMOS static RAM	No	15 ns

1.2.2 Case outlines. The case outlines shall be as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	Descriptive designator	<u>Terminals</u>	Package style
X	CDIP3-T28 or GDIP4-T28	28 28	dual-in-line rectangular leadless chip carrier

1.3 Absolute maximum ratings.

Terminal voltage with respect to ground	-0.5 V dc to +7.0 V dc
DC output current	50 mA
Storage temperature range	-65°C to +150°C
Maximum power dissipation (PD)	1.0 ₩
Lead temperature (soldering, 10 seconds)	+260°C
Thermal resistance, junction-to-case $(\theta_{ic})$ :	
Cases X, Y	See MIL-STD-1835
Junction temperature (T <sub>J</sub> )	+150°C <u>1</u> /

1.4 Recommended operating conditions.

Supply voltage range (V <sub>CC</sub> )	4.5 V dc to 5.5 V dc
High level input voltage range (VIH)	2.2 V dc to 6.0 V dc
Low level input voltage range (VIL)	-0.5 V dc to +0.8 V dc <u>2</u> /
Case operating temperature range (T <sub>C</sub> )	-55°C to +125°C

### 2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standard, and bulletin</u>. Unless otherwise specified, the following specification, standard, and bulletin of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

1/1 Maximum junction temperature may be increased to +175°C during burn-in and steady state life. 2/1 V<sub>IL</sub>(min) = -3.0 V dc for pulse width less than 20 ns.

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MILITARY

MIL-I-38535

- Integrated Circuits (Microcircuits) Manufacturing, General Specification for.

STANDARD

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

MIL-STD-1835

Microcircuit Case Outlines.

BULLETIN

MILITARY

MIL-BUL-103

List of Standardized Military Drawings (SMD's).

(Copies of the specification, standard, and bulletin required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

#### 3. REQUIREMENTS

- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-I-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-I-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-I-38535 is required to identify when the QML flow option is used.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-STD-883 (see 3.1 herein) and herein.
  - 3.2.1 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.
  - 3.2.2 Truth table. The truth table shall be as specified on figure 2.
  - 3.2.3 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.2.4 <u>Die overcoat</u>. Polyimide and silicon coatings are allowable as an overcoat on the die for alpha particle protection provided that each coated microcircuit inspection lot (see MIL-I-38535) shall be subjected to and pass the internal moisture content test, (test method 1018 of MIL-STD-883), the frequency of the internal water vapor testing may not be decreased unless approved by the preparing activity.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.
- 3.5 <u>Marking</u>. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in MIL-BUL-103 (see 6.6 herein).
- 3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.6 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

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■ 9004708 0001332 751 **■** 

## TABLE 1. Electrical performance characteristics.

Test	Symbol	Conditions	Group A	Device	Lin	ii ts	Unit
1651		$-55^{\circ}$ C $\leq$ T <sub>C</sub> $\leq$ +125°C V <sub>CC</sub> = 4.5°V to 5.5°V unless otherwise specified	subgroups	types	Min	Max	
Output high voltage	V <sub>ОН</sub>	V <sub>CC</sub> = 4.5 V, I <sub>OH</sub> = -4.0 mA, V <sub>IL</sub> = 0.8 V, V <sub>IH</sub> = 2.2 V	1,2,3	ALL	2.4		V
Output low voltage	V <sub>OL</sub>	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 8.0 mA V <sub>IL</sub> = 0.8 V, V <sub>IH</sub> = 2.2 V	1,2,3	All		0.4	V
Input leakage current	ILI	$V_{CC} = 5.5 \text{ V, GND} \leq V_{IN} \leq V_{CC}$	1,2,3	All		±10.0	μА
Output leakage current	ILO	V <sub>CC</sub> = 5.5 V, <del>CE</del> = V <sub>IH</sub> , GNO ≤ V <sub>OUT</sub> ≤ V <sub>CC</sub>	1,2,3	All		±10.0	μА
Operating supply	I <sub>CC1</sub>	V <sub>CC</sub> = 5.5 V, <u>CE</u> = 0.8 V,	1,2,3	01-05		120	_  m
current		$V_{CC} = 5.5 \text{ V}, \ \overline{CE} = 0.8 \text{ V}, \\ f = 1/t_{AVQV}, \ OE = 2.4 \text{ V}$		06		150	_
				07		160	1
Standby supply	Irra	V <sub>CC</sub> = 5.5 <u>V</u> , CE = 2.4 V, f = 0 Hz, OE = 2.4 V	1,2,3	01-05		20	_   _
current (TTL)	1/	f° = 0 Hz, OE = 2.4 V		06,07		40	
Standby supply	Iccz	V <sub>CC</sub> = 5.5 V, <del>CE</del> = V <sub>CC</sub> - 0.3 V, f = 0 Hz	1,2,3	01-05		10	_  m
current (CMOS)	1/	f°≌ 0 Hz		06,07	ļ	20	_
Data retention supply current	<sup>1</sup> cc4 <sub>1</sub> /	$V_{CC} = 2.0 \text{ V}, \overline{CE} \ge V_{CC} - 0.2 \text{ V}$ $f = 0 \text{ MHz},$ Applies only to devices with data retention.	1,2,3	01-05		1	П
Input capacitance	CIN	$V_{CC} = 5.0 \text{ V}, V_{IN} = 0 \text{ V},$ $f = 1.0 \text{ MHz}, T_{A} = +25^{\circ}\text{C},$ see 4.3.1c	4	All		11	F
Output capacitance	Соит	V <sub>CC</sub> = 5.0 V, V <sub>OUT</sub> = 0 V, f = 1.0 MHz, T <sub>A</sub> = +25°C see 4.3.1c	4	All		11	
Functional tests		See 4.3.1d	7, 8A, 8E	All			

See footnotes at end of table.

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Test	Symbol	Conditions	Group A	Device	Limits		Unit
		$-55^{\circ}C \le T_{c} \le +125^{\circ}C$ $V_{cc} = 4.5$ V to 5.5 V unless otherwise specified	subgroups	types	Min	Max	
Read cycle time	tavav	See figures 3 and 4 2/	9,10,11	01	70		ns
				02	55	ļ	4
				03	45		_
				04	35		4
				05	25		4
				06	20	-	+
				07	15	-	
Address access time	tAVQV		9,10,11	01	<u> </u>	70	ns
				02		55	+
				03	-	45	+
				04		35	_
				05		25	+
				06		20	+
				07		15	
Output hold from address change	t <sub>AVQX</sub>		9,10,11	All	3.0		ns
Chip select access time	t <sub>ELOV</sub>		9,10,11	01		70	n:
				02		55	_
				03	ļ	45	_
				04		35	_
				05	<u> </u>	25	4
				06	<del> </del>	20	$\dashv$
			-	07	+	15	
Chip select to output in low Z	t <sub>ELQX</sub>	See figures 3 and 4 <u>3</u> / <u>4</u> /	9,10,11	All	3.0		n

See footnotes at end of table.

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**9**004708 0001334 524 **=** 

Test	Symbol	Conditions	Group A	Device	Lin	nits	Unit
,		$-55^{\circ}C \le T_{C} \le +125^{\circ}C$ $V_{CC} = 4.5^{\circ}V$ to 5.5 V unless otherwise specified	subgroups	types	Min	Max	
Chip deselect to output	tEHQZ	See figures 3 and 4 3/4/	9,10,11	_ 01		30	_ ns
in high Z	Enez			02		25	4
				03		20	+
				04,05		15	-
				06		10	-
				07		8	<del> </del>
Output enable to output	toLQV	See figures 3 and 4	9,10,11	01		45	ns
valid				02		35	+
				03		30	4
				04	ļ	25	_
				05		15	-
				06	-	10	-
				07	ļ <u> </u>	8	
Output enable to output in low Z	t <sub>OLQX</sub>	See figures 3 and 4 3/4/	9,10,11	All	0		n
Output disable to output	toHQZ		9,10,11	01		25	_  n
in high Z				02-04	-	20	
				05		15	_
				06,07	-	9	
Write cycle time	tavav	See figures 3 and 5 2/	9,10,11	01	70		_
				02	55		_
				03	45		
				04	35		
				05	25		_
				06	20_		_
			İ	07	15	İ	

See footnotes at end of table.

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Test	Symbol	Conditions	Group A	Device	Limits		Unit
		$-55^{\circ}C \le T_{C} \le +125^{\circ}C$ $V_{CC} = 4.5^{\circ}V$ to 5.5 V unless otherwise specified	subgroups	types	Min	Max	
Chip select to end of	tELEH	See figures 3 and 5 2/	9,10,11	01-03	30		_  ns
write				04	25	<del> </del>	_
				05	20		_
				06	15	ļ	_
		1		07	10		_
Address valid to end of	t <sub>AVWH</sub>		9,10,11	01-03	30		_ ns
write				04	25		_
	į		05	20		_	
				06	15		_
		_		07	10	ļ	
Address setup time	tavwL		9,10,11	ALL	0		ns
Write pulse width	twLwH	-	9,10,11	01-03	30		_ ns
				_04	25		_
				05	20		_
				06	15		_
		_		07	10		
Write recovery time	twhax tehax		9,10,11	All	0		ns
Data valid to end of	t <sub>DVWH</sub>	-	9,10,11	01-04	20		ns
write				05	15		_
				06	10		_
		_		07	9		
Data hold time	twHDX		9,10,11	Att	0		n

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■ 9004708 0001336 3T7 **■** 

TABLE I.	Electrical	performance	characteristics	-	Continued.
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Test	Symbol	Conditions	Group A	Group A Device subgroups types	Limits		Unit
		$-55^{\circ}\text{C} \leq \text{I}_{\text{C}} \leq +125^{\circ}\text{C}$ $\text{V}_{\text{CC}} = 4.5^{\circ}\text{V}$ to 5.5 V unless otherwise specified	subgroups		Min	Max	
Write enable to output	twLQZ	See figures 3 and 5 3/4/	9,10,11	01		30	ns
in high Z				_02		25	_
				03		20	
				04,05		15	
				06		10	_
				07		7_	
Output active from end of write	t <sub>w</sub> HQX		9,10,11	All	0		ns
Chip deselect to data retention time	<sup>t</sup> CDR	CS > V <sub>CC</sub> -0.2 V, see figure 6 3/	9,10,11	All	0		ns
Operation recovery time	t <sub>R</sub>		9,10,11	ALL	tavav		ns

<sup>1/</sup> At f = f<sub>MAX</sub> address and data inputs are cycling at the maximum frequency of read cycles of 1/t<sub>AVAV</sub>. f = 0 means no input lines change.
2/ Test conditions assume signal transition times of 5.0 ns or less. Timing is referenced at

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<sup>2/</sup> Test conditions assume signal transition times of 5.0 ns or less. Timing is referenced at input and output levels of 1.5 V and input pulse levels of 0 to 3.0 V. Output loading is equivalent to the specified I<sub>OI</sub>/I<sub>OH</sub> with a load capacitance of 30 pF.
3/ If not tested, shall be guaranteed to the limits specified in table I.

<sup>4/</sup> Test conditions assume signal transition times of 5.0 ns or less. Transition is measured at steady-state high level of -500 mV or steady-state low level of +500 mV on the output from 1.5 V level on the input with a load capacitance of 5.0 pF.

,	ILL
х	Y
	ninal pol
NC A0 A1 A2 A4 A5 A6 A7 A8 A9 CE OE OE OF OF OF OF OF OF OF OF OF OF OF OF OF	NC A1 A2 A4 A5 A7 A89 CEE OEND NC 1/023 1/04 A11 A13 A15 NC VCC
	X Term symbol

NC = no connection

Figure 1. <u>Terminal connections</u>.

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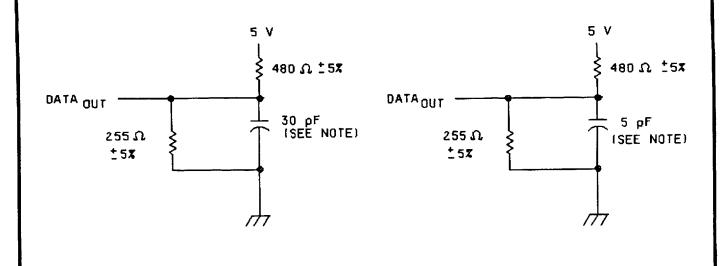
■ 9004708 0001338 17T **■** 

Mode	CE	WE	ŌĒ	OUTPUTS	Power
Standby	Н	х	х	High Z	Standby
Read	<u> L</u>	н	<u> </u>	Data Out	Active
Write	L_	L	х	Data In	Active
Deselect	L	н	н	High Z	Active

Figure 2. <u>Truth table.</u>

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**■** 9004708 0001339 006 **■** 



CIRCUIT A

CIRCUIT B

Output load

(for t<sub>OLQX</sub>, t<sub>ELQX</sub>, t<sub>OHQZ</sub>, t<sub>WLQZ</sub>, t<sub>EHQZ</sub>, t<sub>WHQX</sub>)

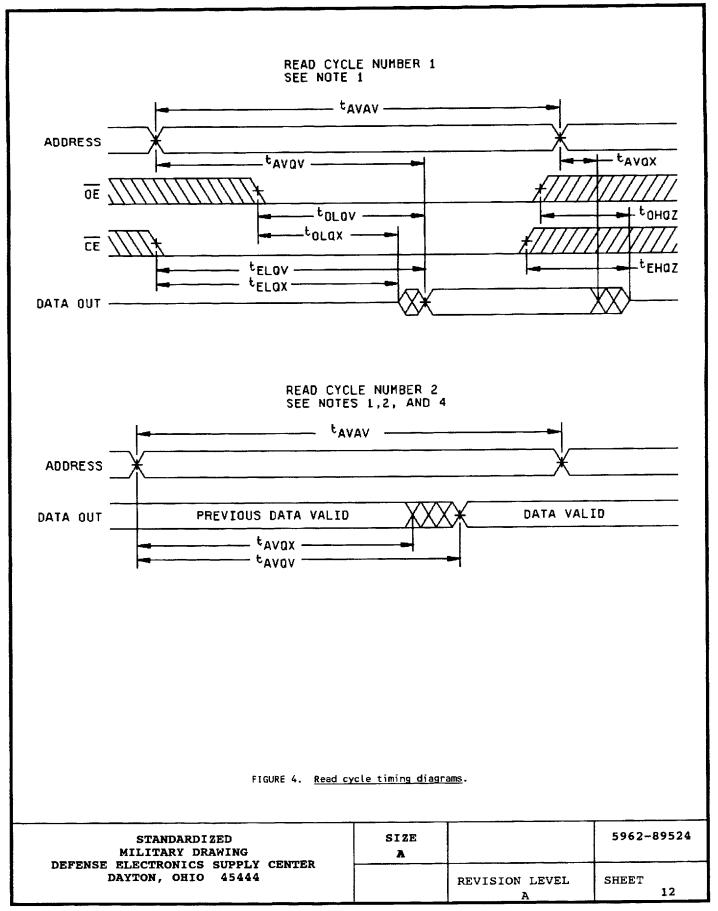
NOTE: Including scope and jig (minimum values).

FIGURE 3. Output load circuit.

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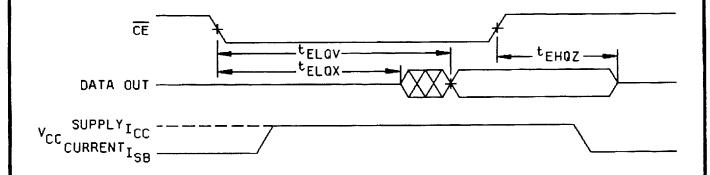
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## READ CYCLE NUMBER 3 SEE NOTES 1,3, AND 4



## NOTES:\_

1. WE is high for read cycle.

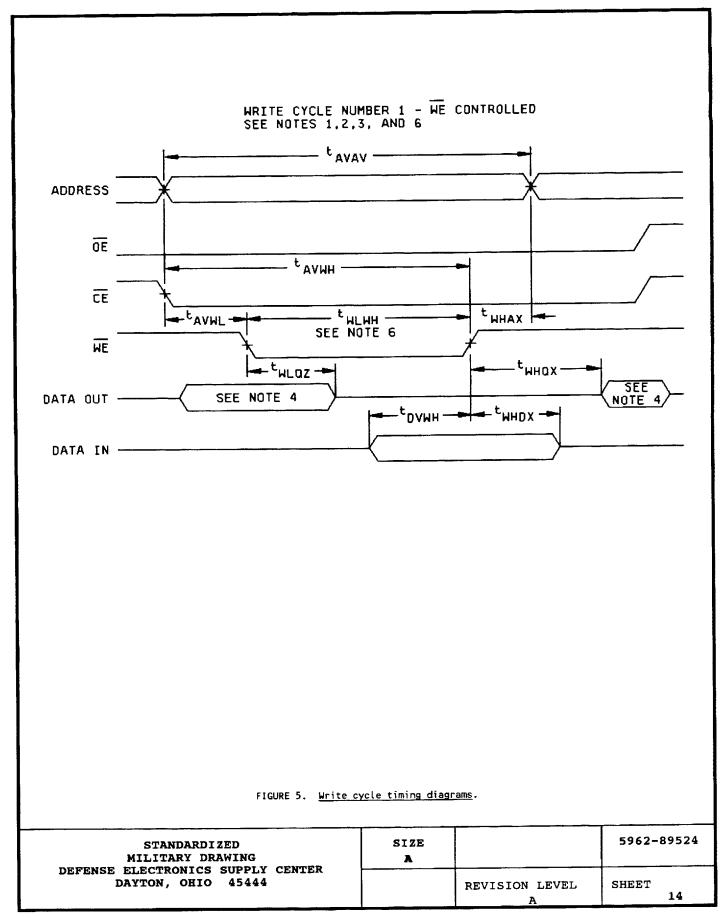
WE is might for redu cycle.
 Device is continuously selected. CE = V<sub>IL</sub>.
 Address valid prior to or coincident with CE transition low.
 OE = V<sub>IL</sub>.

FIGURE 4. Read cycle timing diagrams - continued.

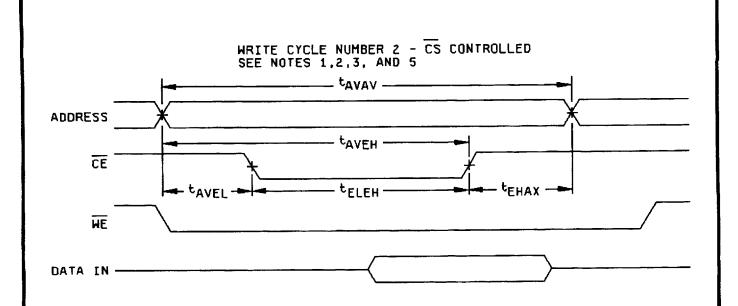
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NOTES:

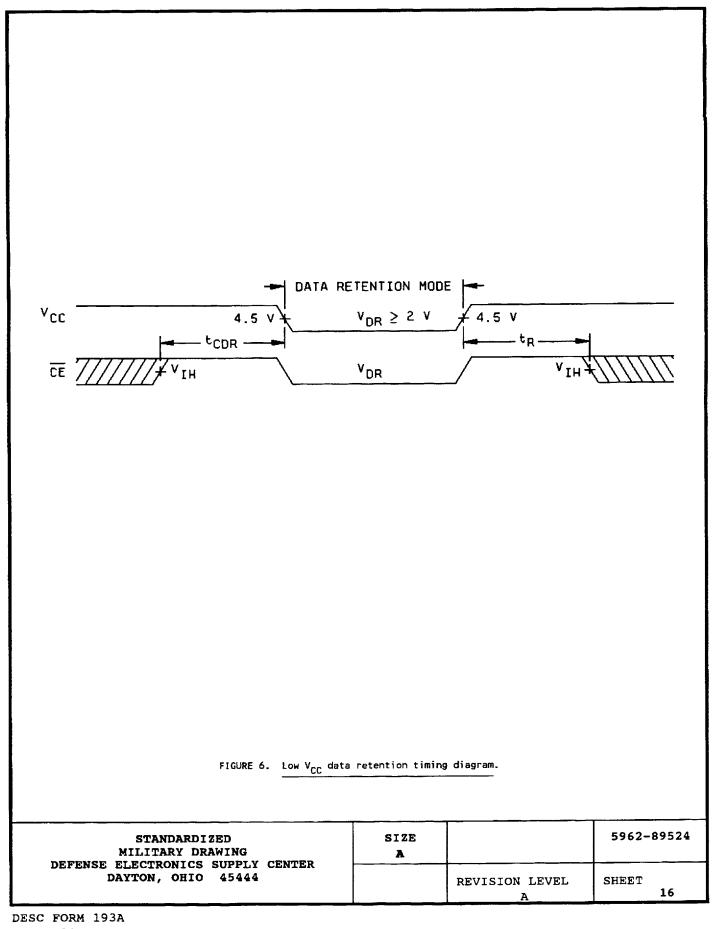
- 1.  $\overline{\text{WE}}$  or  $\overline{\text{CE}}$  must be high during all address transitions.
- 2. A write occurs during the overlap ( $t_{\rm ELEH}$  or  $t_{\rm WLWH}$ ) of a low  $\overline{\rm CE}$  and a low  $\overline{\rm WE}$ .
- t<sub>WHAX</sub> is measured from the earlier of CE or WE going high to the end of the write cycle.
   During this period, the I/O pins are in the output state, and input must not be applied.
   If the CE low transition occurs simultaneously with or after the WE low transition, the outputs remain in the high\_impedance state.
- 6. If OE is low during a WE controlled write cycle, the write pulse width must be the larger of twww or (two) to allow the I/O drivers to turn off and data to be placed on the bus for required to If OE is high during a WE controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified twww.

FIGURE 5. Write cycle timing diagrams - continued.

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■ 9004708 0001345 3DT ■

### TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*,2,3,7*,8A,8B, 9,10,11
Group A test requirements (method 5005)	1,2,3,4**,7,8A, 8B,9,10,11
Groups C and D end-point electrical parameters (method 5005)	2,3,7,8A,8B

- PDA applies to subgroups 1 and 7.
- \*\* See 4.3.1c
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 <u>Notification of change</u>. Notification of change to DESC-EC shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.9 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
  - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
  - a. Burn-in test, method 1015 of MIL-STD-883.
    - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-SID-883.
    - (2)  $T_A = +125$ °C, minimum.
  - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

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### 4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 ( $C_{IN}$  measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.
- d. Subgroups 7 and 8 shall include verification of the truth table.

### 4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
  - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-SID-883.
  - (2)  $T_A = +125$ °C, minimum.
  - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

### 5. PACKAGING

5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-STD-883 (see 3.1 herein).

### 6. NOTES

- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.
- 6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and the applicable SMD. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444-5270, or telephone (513) 296-5377.
- 6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-EC.

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